



Prof. Seok-Hee Lee

SK On, President and CEO

Seok-Hee Lee received the B.S. and M.S. degrees in Materials Science and Engineering from Seoul National University, Seoul, Korea, in 1988 and 1990, respectively, and the Ph.D. degree in Materials Science and Engineering from Stanford University, Stanford, CA. in 2000. Since December 2023, he is leading SK On, as President and CEO.

From 1990 to 1995, he was with the Advanced Semiconductor Development group, Hyundai Electronics (now SK hynix), Korea, where he worked in the area of gate oxide scaling and reliability. From 2000 to 2010, he was with the Portland Technology Development group, Intel Corporation, Hillsboro, OR, where he worked on process integration and yield on Intel's 130-, 90-, 65-nm, and 32 nm advanced CMOS logic technologies. Dr. Lee has received the Intel Achievement Award three times (Intel's highest recognition for technical achievement) and 11 Intel Divisional Recognition Awards for his technical achievements in transistor and process development.

From 2010 to 2013, he was with the the department of electrical engineering in KAIST, Korea, as an associate professor. His main research was on nano-scale devices and fabrication. Professor Lee received the best teaching award in 2011.

In February 2013, he joined SK hynix as an executive vice president and returned to the industry, leading the Future Technology Research Center and overseeing new semiconductor technologies and process development. He was promoted to Executive Vice President and Head of DRAM Development at SK hynix in 2014. In 2018, he was appointed CEO of SK hynix, and served in that role until 2022.

As President and CEO of SK On, Dr. Seok-Hee Lee is now focusing his management efforts on the SK Group's next-generation growth engine focused on the battery business.